Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type $(\pi - MOSVII)$

TK15J50D

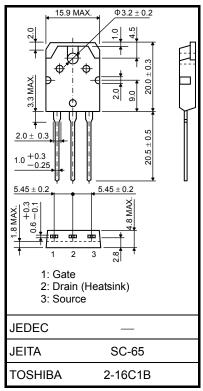
Switching Regulator Applications

• Low drain-source ON resistance: RDS (ON) = 0.33Ω (typ.)

- High forward transfer admittance: $|Y_{fs}| = 8.0 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 500 \text{ V)}$
- Enhancement-mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V (VDS} = 10 \text{ V, ID} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|--|----------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | 500 | V | |
| Gate-source voltage | | V_{GSS} | ±30 | V | |
| Drain current | DC (Note 1) | ID | 15 | Α | |
| | Pulse (Note 1) | I _{DP} | 60 | _ ^ | |
| Drain power dissipati | on (Tc = 25°C) | P _D | 210 | W | |
| Single pulse avalanche energy (Note 2) | | E _{AS} | 360 | mJ | |
| Avalanche current | | I _{AR} | 15 | Α | |
| Repetitive avalanche energy (Note 3) | | E _{AR} | 21 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature range | | T _{stg} | -55 to 150 | °C | |



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.595 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W |

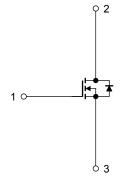
Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 2.72 mH, R_G = 25 Ω , I_{AR} = 15 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Internal Connection



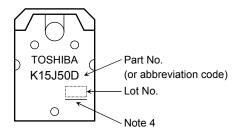
Electrical Characteristics (Ta = 25°C)

| Chara | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|---------------|----------------------|---|-----|------|-----|------|
| Gate leakage current | | I _{GSS} | $V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±1 | μА |
| Drain cut-off current | | I _{DSS} | V _{DS} = 500 V, V _{GS} = 0 V | _ | _ | 10 | μА |
| Drain-source breakdown voltage | | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 500 | _ | _ | V |
| Gate threshold vo | oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source ON | resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 7.5 A | _ | 0.33 | 0.4 | Ω |
| Forward transfer | admittance | Y _{fs} | V _{DS} = 10 V, I _D = 7.5 A | 2.0 | 8.0 | _ | S |
| Input capacitance | | C _{iss} | | _ | 1800 | | pF |
| Reverse transfer capacitance | | C _{rss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | _ | 9 | | |
| Output capacitance | | C _{oss} | | | 190 | | |
| Switching time | Rise time | t _r | V_{GS} V_{OD} $V_{DD} \approx 200 \text{ V}$ | _ | 40 | _ | ns |
| | Turn-on time | t _{on} | | | 80 | | |
| | Fall time | t _f | | | 15 | | |
| | Turn-off time | t _{off} | Duty ≤ 1%, t _W = 10 μs | _ | 110 | _ | |
| Total gate charge | | Qg | | _ | 38 | _ | |
| Gate-source charge | | Qgs | $V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$ | _ | 24 | _ | nC |
| Gate-drain charge | | Q _{gd} | | _ | 14 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

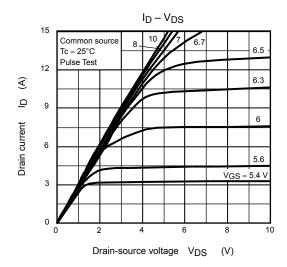
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 15 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 60 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 15 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | $I_{DR} = 15 \text{ A}, V_{GS} = 0 \text{ V},$ | _ | 1200 | _ | ns |
| Reverse recovery charge | Q _{rr} | dI _{DR} /dt = 100 A/μs | _ | 13 | _ | μС |

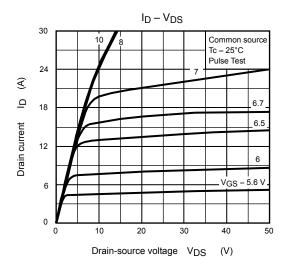
Marking

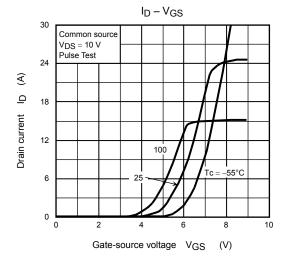


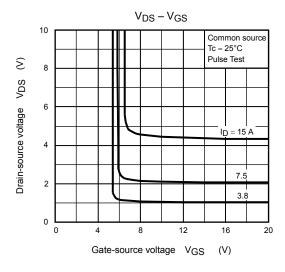
Note 4: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

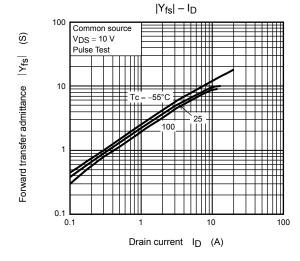
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

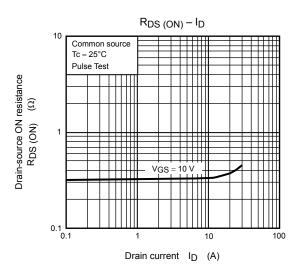


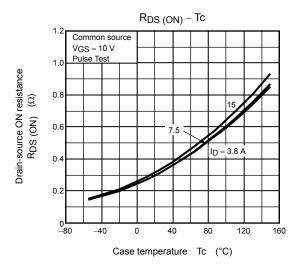


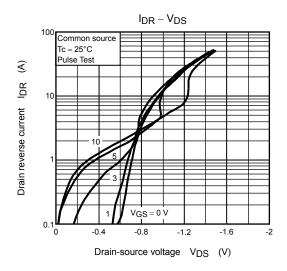


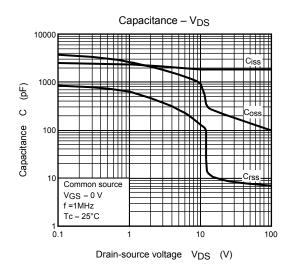


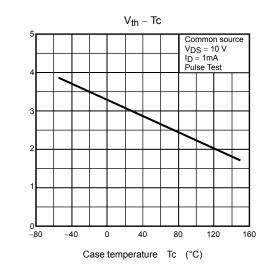


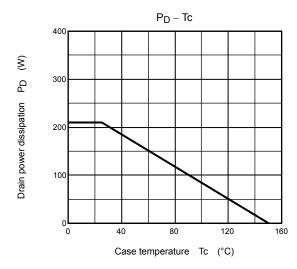


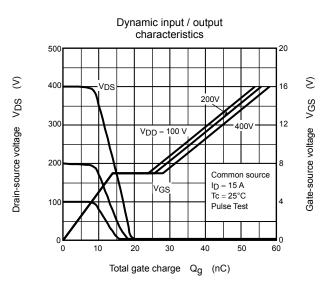






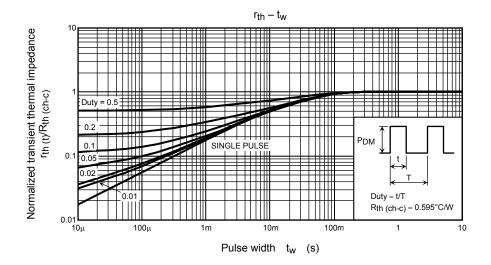


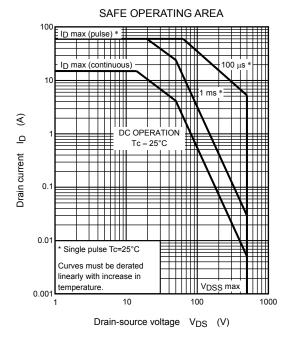


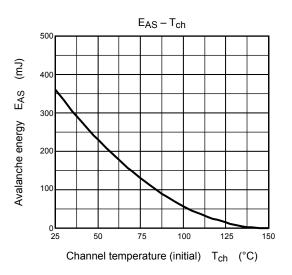


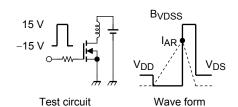
 $\widehat{\mathbb{S}}$

Gate threshold voltage Vth









$$R_G = 25 \Omega$$

 $V_{DD} = 90 \text{ V, L} = 2.72 \text{ mH}$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right)$$

5 2011-04-25

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